

SPECIFICATIONS

PDF DATA SHEET

EFORCEAUSTRALIA PTY.LTD ACN:159 503 401

MLL-III-885/1~2000mW

LOW NOISE INFRARED DIODE LASER AT 885 nm

Low noise diode infrared laser module at 885 nm is made features of ultra compact, long lifetime, low cost and easy operating, which is used in measurement, communication, spectrum analysis, etc.



SFECIFICATIONS			
Wavelength (nm)	885 ± 5		
Output power (mW)	>1, 50, 100, , 2000		
Transverse mode	Near TE ₀₀		
Operating mode	CW		
Power stability (rms, over 4 hours)	<1%, <3%, <5%		
Noise of amplitude(rms,1~20MHz)	<1%		
Warm-up time (minutes)	<5		
M ² factor	<20		
Beam divergence, full angle (mrad)	<3.0		
Dimensions of beam at the aperture (mm)	~5×8		
Beam height from base plate (mm)	24.8		
Polarization ratio	>50:1		
Pointing stability after warm-up (mrad)	<0.05		
Operating temperature (°C)	10~35		
Power supply (90-264VAC or 5VDC)	PSU-III-LED	PSU-III-FDA	PSU-III-OEM
Expected lifetime (hours)	10000	•	
Warranty	1 year		





MxL-III-885	PSU-III-LED	PSU-III-FDA	PSU-III-OEM
136(L)×73(W) ×46. 2(H) mm ³ , 0.6kg	153 (L) ×155(W) ×92 (H) mm ³ , 1.5kg	DPSSL DRIVER	100 (L) ×62(W) ×56 (H) mm ³ , 0.2kg
← 59 - →	155		
-4-15°6.5			
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